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PTO/S8/08a (08-03)

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U.S. Patent and Trademark Office: U.S. DEPARTMENT OF COMMERCE

2005

June

Under the Panerwork Reduction Act of 1995, no persons are required to respo 10/688,420-797 **Application Number** Substitute for form 1449A/PTO October 17, 2003 Filing Date Singh, et al. First Named Inventor SUPPLEMENTAL INFORMATION **DISCLOSURE STATEMENT BY** 1762 **Group Art Unit APPLICANT** Examiner Name Unknown AMAT/7729/TCG/EPI/RKK Attorney Docket Number (Use as many sheets as necessary)

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Examiner Initials*	Cite	Document Number	Publication Date MM-OD-YYYY	Name of Patentee or	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear			
	No.1	Number-Kind Code <sup>2 (9 known)</sup>		Applicant of Cited Document				
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Examiner Initials*	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published	T²		
	C1	Kamins, et al. "Kinetics of selective epitaxial deposition of Si <sub>1-x</sub> Ge <sub>x</sub> ", Applied Physics Letters, American Institute pf Physics. New York, US, vol. 61, no. 6, 10 August 1992, pp. 689-871			
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I Inder the Panerwork Reduction Act of 1995, no nections are remained to res 10/688,426 Application Number Substitute for form 1449A/PTO October 17, 2003 Filing Date Singh, et al. SUPPLEMENTAL INFORMATION First Named Inventor **DISCLOSURE STATEMENT BY** Group Art Unit 1762 **APPLICANT** Unknown **Examiner Name** AMAT/7729/TCG/EPI/RKK Attorney Docket Number (Use as many sheets as necessary)

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		NON PATENT LITERATURE DOCUMENTS		
Examiner Initials*	Cite No. <sup>1</sup>	Cite No.¹  Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published		
	СЗ	Sedgwick, et al. "Selective SiGe and heavily As doped Si deposited at low temperature by atmospheric pressure chemical vapor deposition", Journal of Vacuum Science and Technology: Part B, American Institute of Physics. New York, US, vol. 11, no. 3, 1 May 1993, pp. 1124-1128	7	
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